scientific reports



OPEN Demonstration of a MOT in a sub-millimeter membrane hole

Jongmin Lee[™], Grant Biedermann, John Mudrick, Erica A. Douglas & Yuan-Yu Jau

We demonstrate the generation of a cold-atom ensemble within a sub-millimeter diameter hole in a transparent membrane, a so-called "membrane MOT". With a sub-Doppler cooling process, the atoms trapped by the membrane MOT are cooled down to 10 µK. The atom number inside the unbridged/ bridged membrane hole is about 10^4 to 10^5 , and the $1/e^2$ -diameter of the MOT cloud is about $180 \,\mu m$ for a 400 µm-diameter membrane hole. Such a membrane device can, in principle, efficiently load cold atoms into the evanescent-field optical trap generated by the suspended membrane waveguide for strong atom-light interaction and provide the capability of sufficient heat dissipation at the wavequide. This represents a key step toward the photonic atom trap integrated platform (ATIP).

The past two decades have witnessed remarkable advances in computing and sensing with demonstrations that leverage coherence and entanglement in systems well-described by quantum mechanics^{1,2}. Concurrently, the advent of microfabrication techniques promises new frontiers in quantum applications³⁻⁵ through atomlight interactions⁶⁻¹⁷ such as incorporating compact magneto-optical traps (MOTs)¹⁸⁻²⁶ on atom chips²⁷⁻³⁴ and superconducting circuits³⁵⁻⁴⁰. Quantum engineering of integrated quantum systems has seen the development of compact and scalable laser systems using hybrid integrated photonic circuits 41,42 with silicon photonics, III-V photonics, and nonlinear optics. Such techniques are poised to facilitate reliable operation of cold-atom positioning, navigation and timing (PNT) sensors⁴³ in new and challenging environments. Engineering of quantum systems has also enabled integrated, on-chip quantum computing platforms capable of individual spin addressing, spin-spin entanglement and spin readout. Quantum processors with more than 50 qubits have been demonstrated with superconducting circuits^{44,45}. Likewise, new efforts are exploring novel surface ion-trap platforms^{46,47} combining microfabricated surface electrodes and integrated photonics on the same chip. These quantum engineering efforts aim to implement a quantum-to-classical interface⁴⁸ and leverage conventional computing and control systems to achieve optimum performance of integrated quantum systems across multiple platforms.

Membrane MOT devices compatible with photonic integrated circuits (PIC) technology⁴⁹ can pave the way toward atom trap integrated platforms (ATIP)⁵⁰ for neutral atoms. In this architecture, the suspended membrane waveguide can be used to trap and probe neutral atoms through the evanescent fields of optical waveguide modes, which is capable of delivering sufficient optical powers in vacuum while the membrane structure attached to the silicon substrate dissipates the heat generated from optical absorption in the waveguide. This heat dissipation capability could eliminate the need for the fabrication of optical waveguides on the substrate¹¹⁻¹³. Photonic ATIPs will be crucial for enabling future neutral atom quantum applications. Atomic spins positioned near the waveguide surface offer an interface between spin information and the guided optical mode which can be processed in the PIC. Compared to artificial counterparts^{51,52}, neutral atoms offer powerful and compelling advantages in terms of homogeneous physical properties and long coherence and life times due to being well-isolated from noise sources. Compared to trapped ion approaches, neutral atoms offer near-term scaling advantages, larger atomic ensembles and a wide range of sensing modalities.

In this paper, we demonstrate a foundational technique for laser cooling atoms directly in the vicinity of an optical waveguide that can act as an information bus. This approach is advantageous in terms of technical simplicity and efficacy. In particular, efficient atom loading near the suspended membrane waveguide is crucial for positioning and coupling many atoms to the evanescent-field guided mode. In doing so, we can bring the success of evanescent-field optical traps around a nanofiber 53-56 to the photonic ATIP with unique features and new possibilities. Underpinning our approach is our introduction of a MOT produced in a sub-millimeter diameter hole on a microfabricated transparent membrane. The membrane itself can support an optical waveguide that traverses the hole, allowing the optical field to interact with the atomic spins via the evanescent field extending into the vacuum. In our demonstration, we imitate such a waveguide with a three-micrometer-width mechanical beam fabricated from the membrane material, allowing us to test the atom loading dynamics around such a structure.

In our system⁵⁷, we reimagine the interface between a MOT and a device with a transparent membrane that divides the MOT loading volume in two and collects cold atoms in a sub-millimeter hole in the membrane.

Sandia National Laboratories, Albuquerque, NM 87185, USA. [™]email: jongmin.lee@sandia.gov

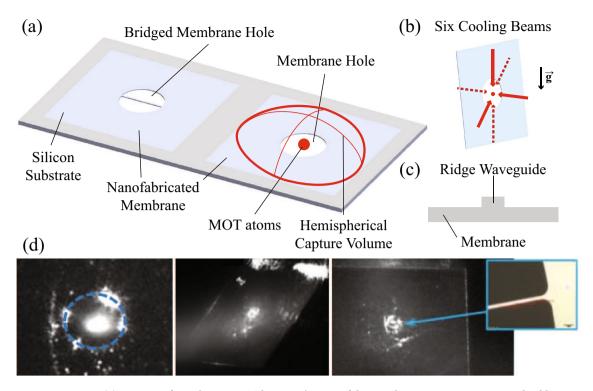


Figure 1. (a) Concept of membrane MOT devices. The area of the membrane is 5 mm \times 5 mm, and cold atoms in a membrane MOT can be generated in a sub-millimeter diameter membrane hole using six 3.8 mm diameter laser cooling beams, i.e., MOT beams. The bridged membrane hole has a dummy waveguide which imitates a 3- μ m-width membrane ridge waveguide. (b) Six MOT beam configuration for a membrane MOT. (c) Concept of the membrane ridge waveguide. (d) (Left) Image of laser-cooled atoms at the center of a membrane hole without a dummy waveguide. (Middle, Right) Images of laser-cooled atoms at a bridged membrane hole. The diameter of the unbridged/bridged membrane hole is 400 μ m in both.

According to our simulations (see Fig. 20 in Ref. 57), through laser cooling, atoms dissipate kinetic energy and relax into the center of the trap without entering the other hemisphere. Thus, many atoms eventually accumulate at the center of the membrane hole. The size or localization of membrane MOT atoms is limited by the size of the membrane hole, which can be readily sub-millimeter, whereas the size of the membrane itself can be orders of magnitude larger and define a generous loading volume. Using the membrane MOT with the 400 μ m-hole diameter, we loaded about 10^5 atoms into the hole. Furthermore, this geometry is compatible with sub-Doppler cooling mechanisms $^{58-61}$ and we observe $\sim 10~\mu$ K temperature in our setup. Our membrane MOT approach offers a convenient means for positioning a large number of trapped atoms around microfabricated light guiding structures in the plane of an ATIP.

Experimental setup and membrane fabrication

In the experiment, 133 Cs atoms were used for the free-space and membrane MOTs with cooling and repump beams (852 nm, D2 transition) and an absorption probe (895 nm, D1 transition). The vacuum setup was configured with a glass chamber (40 mm × 40 mm × 100 mm), a mini-cube and a 5 L/s ion pump, resulting in a pressure of 10^{-8} mbar. The entire chamber, and hence the samples, were moved with a 1D lab-jack and a 2D translation stage and aligned to the free-space MOT. Six intensity-balanced collimated MOT beams ($< 4 \, \text{mm} \, 1/e^2$ diameter) pass through the transparent membrane (5 mm × 5 mm) and can be precisely aligned to the membrane hole, i.e., the MOT loading zone, using multiple 2D translation stages. As shown in Fig. 1b, four horizontal laser cooling beams cool atoms in the horizontal plane, and two vertical laser cooling beams cool atoms along the vertical axis, i.e., the gravity direction. The transparent membrane captures atoms with two large hemispherical capture volumes as shown in Fig. 1a and loads MOT atoms into the sub-millimeter membrane hole. Two rods support the aluminum membrane sample holder with \sim 40 degree angle, allowing the MOT beams to pass through the membrane without being occluded by the silicon substrate. The symmetry axis of quadrupole MOT coils is aligned to the vertical axis, i.e., the gravity direction. We checked Doppler-cooling and sub-Doppler cooling of the free-space MOT and the membrane MOT with and without a dummy waveguide at the center hole.

We used two membranes made of AlN (aluminum nitride) and SiN (silicon nitride) for the experiments. Importantly, the thermal conductivity of AlN is 10 times higher than SiN, which can be advantageous in terms of heat dissipation of a suspended waveguide. The absorption loss of membrane ridge waveguides (Fig. 1c) needs to be considered because it is the main cause of heat generation at the suspended waveguide section. The fabrication process of the membrane MOT devices⁵⁷ is shown in Fig. 2. Tensile SiN/AlN films were deposited on the front side of a silicon wafer. Front-side SiN was deposited via low pressure chemical vapor deposition

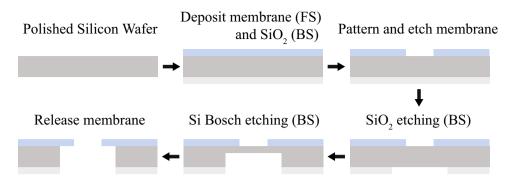


Figure 2. Membrane fabrication process of SiN and AlN; FS is the front side, the top of a silicon wafer, and BS is the back side, the bottom of a silicon wafer. The thickness of membranes is 200 nm, and the membrane transmittance is greater than 95% at 852 nm wavelengths (laser cooling light for Cs atoms).

(LPCVD) while AlN was deposited via reactive sputter physical vapor deposition (PVD). SiO_2 (silicon dioxide) was deposited via plasma enhanced chemical vapor deposited (PECVD) on the back side of the wafer to be used as a hard mask for Si Bosch etching. Both front and back sides were patterned by conventional photolithography. SiN films (or AlN films) were patterned and etched with fluorine-based (or chlorine-based) inductively coupled plasma reactive-ion etching (ICP-RIE) to define the membrane geometry. The back-side SiO_2 was then patterned and etched with fluorocarbon-based ICP-RIE. The Si wafer was etched from the back-side using patterned SiO_2 as a mask in a deep reactive ion etch (DRIE) Bosch process, leaving approximately SO_1 m of SI_2 below the patterned membrane region. Final membrane release was accomplished by a KOH (potassium hydroxide) wet etch for SIN_1 membranes, and SI_2 (xenon difluoride) dry release for AlN membranes. Depending on the shape of a membrane hole, a specific shape of the membrane MOT can be prepared to interface the atoms through integrated photonics/electronics.

Trapping and sub-Doppler cooling of atoms in a sub-millimeter membrane hole

We characterized three different MOT configurations as follows: (1) free space, (2) unbridged membrane hole (see Fig. 1d: Left), and (3) bridged membrane hole (see Fig. 1d: Middle, Right). Membrane MOT devices can trap atoms in sub-millimeter diameter holes and we compared steady-state atom number, loading rate, lifetime and sub-Doppler cooled atom temperature to the free-space MOT. The same laser cooling beams, i.e., MOT beams, (852 nm, Cs D2 transition) were used for all the MOT measurements with and without the membrane geometry affecting those characterization results. The localization of membrane MOT atoms is determined by the geometry of the membrane hole and the transparent membrane. The transparent membrane (5 mm \times 5 mm) effectively provides a larger loading zone (i.e., MOT beams) compared to the membrane hole diameter but restricts atom trajectories. Therefore, most of the membrane MOT atoms are accumulated at the membrane hole ($d_{Hole} \leq 1$ mm).

The measured steady-state atom number is shown in Fig. 3. The MOT atom number at the membrane hole decreased by about 5-to-10 times compared to the free-space MOT ($d_{MOT}=3.8\,\mathrm{mm}$), which may result from lower atom loading rate near the membrane device (see Fig. 4a). Bridged membrane MOT devices with a comparable loading rate to the unbridged membrane devices show lower atom numbers than that of the membrane MOT devices at the membrane hole due to a lower $1/\beta$ MOT lifetime (see Fig. 4b). The atom number was not strongly affected by the type of membrane (AlN or SiN). The transmittance of membranes should be maximized for a target wavelength, e.g., a laser cooling beam. Using 200 nm-thick AlN and SiN membranes, the transmittance at 852nm wavelengths is greater than 95%, effectively providing two complete hemispherical capture volumes for Cs atoms. The transmittance depends on the thickness and refractive index of the membrane and the light wavelength. In addition, the membrane thickness and the height of the membrane ridge can affect the evanescent-field mode of the suspended membrane ridge waveguides⁴⁹.

The optical intensity of Gaussian beams is defined as $I(r,z)=2P/(\pi\,w(z)^2)\exp(-2r^2/w(z)^2)$, and the beam radius w(z) is the distance from the maximum intensity where the intensity drops to $1/e^2(\approx 13.5\%)$. The optical power of each MOT beam is $P=2.6\pm0.2\,\mathrm{mW}$, and the beam diameter of the MOT beam is $d_{MOT}=2w(z)\approx 3.8\,\mathrm{mm}$ in free space. Therefore, the free-space intensity of the MOT beam is $I=(41.7\pm3.2)\,I_{sat}$, where $I_{sat}=1.1\,\mathrm{mW/cm^2}$ and $\Gamma=2\pi\cdot5.2\,\mathrm{MHz}$ (FWHM) for the $^{133}\mathrm{Cs}$ D2 transition at 852 nm. The detuning of MOT beams is $\delta=-2\Gamma$ and the magnetic field gradient of the MOT coils is $dB/dz\approx 13.6\,\mathrm{G/cm}$. Using an absorption probe (895 nm, Cs D1 transition), we measure 6.2×10^5 atoms in the free-space MOT ($d_{MOT}=3.8\,\mathrm{mm}$), 9.2×10^4 atoms in the unbridged membrane MOT ($d_{Hole}=0.4\,\mathrm{mm}$), and 2.1×10^4 atoms in the bridged membrane MOT ($d_{Hole}=0.4\,\mathrm{mm}$) as shown in Fig. 3.

The main difference between a free-space MOT and a membrane MOT is the localization of cold atoms. Most of the atoms in the membrane MOT exist within the boundary of a sub-millimeter hole due to the restriction of atom trajectories by the transparent membrane, which leads to the smaller size of a MOT cloud; the $1/e^2$ -diameter of a MOT cloud is $180 \pm 6 \,\mu m$ for $d_{Hole} = 0.4 \, mm$. In the case of a free-space MOT, the localization of cold atoms needs to define a finite MOT capture volume with the MOT beam diameter. It is well known that

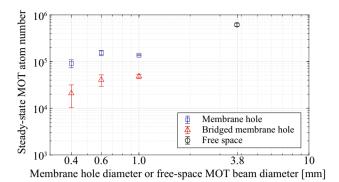
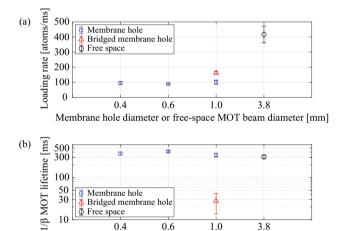


Figure 3. Steady-state MOT atom number versus membrane hole diameter (d_{hole}) or free-space MOT beam diameter (d_{MOT}) . The d_{MOT} comes from the $1/e^2$ Gaussian beam diameter and the d_{hole} comes from the etched hole diameter of the membrane MOT devices. The six-beam MOTs were generated by cooling beams, i.e. MOT beams, and a repump beam in Cs atoms (852 nm, D2 transition). Steady-state MOT atom numbers were measured in the free space (black circle), the membrane hole (blue square), and the bridged membrane hole (red triangle) using an absorption probe (895 nm, D1 transition). We used a 3.8 mm beam diameter (d_{MOT}) for the free-space MOT and 0.4, 0.6, 1.0 mm diameter membrane holes (d_{Hole}) for the membrane MOT and the bridged membrane MOT. The bridged membrane MOT experimentally simulates the situation of a 3-μm-width membrane ridge waveguide across the membrane hole.

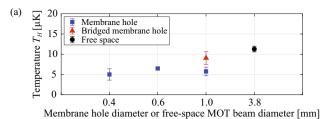


Membrane hole diameter or free-space MOT beam diameter [mm]

Figure 4. (a) Loading rate versus membrane hole diameter or free-space MOT beam diameter. (b) MOT lifetime versus membrane hole diameter (or free-space MOT beam diameter). We measured the loading rates and lifetimes of generated MOT atoms in the free space (black circle), the membrane hole (blue square), and the bridged membrane hole (red triangle). Loading rate and MOT lifetime were measured with an absorption probe. We used 3.8 mm diameter beams (d_{MOT}) for the free-space MOT (black circle) and 0.4, 0.6, 1.0 mm-diameter membrane holes (d_{Hole}) for the membrane MOT (blue square) and the bridged membrane MOT (red triangle). The bridged membrane MOT experimentally simulates the situation of a 3-μm-width membrane ridge waveguide across the membrane hole.

the number of atoms accumulated in a MOT scales unfavorably with MOT beam diameter $^{62-64}$, especially below 2 mm where the scaling converts from $1/d^{3.6}$ to $1/d^{6}$. Hence, attempting to make a free-space MOT with a submillimeter $1/e^{2}$ -diameter Gaussian beam results in a negligible number of atoms. The efficacy of the membrane MOT approach can be shown in a higher atom number localized within a membrane hole compared to the atom number in the free-space MOT specified by a MOT beam diameter which can localize atoms within the same size of the membrane hole. The membrane MOT is better at trapping atoms in a small volume compared to shrinking down the free-space MOT beams.

Based on the loading rate and lifetime measurement of the membrane and free-space MOTs, we found that the vacuum limited lifetime is the same near and far from the membrane in the case of no waveguide bridge, shown in Fig. 4. The loading rate drops by about four near the membrane hole leading to the smaller atom number. The loading rate is affected by the capture velocity, v_c , of the MOT⁶³, and v_c is a function of intensity, optical detuning, and diameter of the MOT beams, magnetic-field gradient, and the physical structure at the



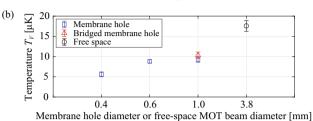


Figure 5. Sub-Doppler cooled temperature of MOT atoms versus membrane hole diameter or free-space MOT beam diameter. (a) Temperature T_H , the temperature of atoms on the horizontal plane. (b) Temperature T_V , the temperature of atoms along the vertical axis. For this, we performed a millisecond of polarization gradient cooling. We used 3.8 mm diameter beams (d_{MOT}) for the free-space MOT (black circle) and 0.4, 0.6, 1.0 mm-diameter membrane holes (d_{Hole}) for the membrane MOT (blue square) and the bridged membrane MOT (red triangle). The bridged membrane MOT experimentally simulates the situation of a 3-μm-width membrane ridge waveguide across the membrane hole.

MOT. It is fair to assume that the membrane structure further limits v_c and therefore reduce the loading rate as shown in Fig. 4a. In addition, the Cs vapor density in our experimental vacuum chamber is much lower than the saturation vapor pressure at room temperature. Under this condition, Cs vapor continuously deposit onto the membrane surface, which causes low near surface vapor density⁶⁵. The MOT lifetime limited by collisions with background Cs atoms is therefore a bit longer, as shown in Fig. 4b. The bridged membrane hole decreases the MOT lifetime (see Fig. 4b) due to the collision between cold atoms and the dummy waveguide, leading to a smaller steady-state atom number.

The usual MOT loading equation 66 is $N(t) = \frac{\alpha}{\beta}(1-e^{-\beta t})$, where α is loading rate (atoms/ms) and $1/\beta$ is MOT lifetime (ms). The steady-state MOT atom number, α/β , is determined by loading rate α and loss rate β . Similar to a reference 67 , the atom number in the MOT is affected by the position of MOT atoms relative to the surface. When the MOT atoms approach the surface within ~ 100 -µm distance, the MOT atom number significantly decreases because of atomic collisions with the surface.

The membrane MOT is always centered inside the hole. The distance to the cloud from the membrane hole edge is a half of the hole diameter such as 200, 300, 500 μ m for $d_{Hole}=0.4, 0.6, 1.0$ mm (photolithography mask pattern). As shown in Fig. 4a, loading rates of MOT atoms decrease by a factor of four near the membrane due to the reduced capture velocity compared to the free-space MOT, which leads to the smaller steady-state atom number. In addition, the MOT lifetime of the bridged membrane MOT device (red triangle) is significantly lower than other cases, and other membrane MOT devices (blue square) have similar MOT lifetimes to the free-space MOT ($d_{MOT}=3.8$ mm) MOT as shown in Fig. 4b. Collisions of atoms with the waveguide surface is a likely contributing factor in the higher loss rate. Other possibilities include a reduced effective capture volume (partially blocked MOT beams; reduced intensity and impure polarization of MOT beams to pass through the membrane, surface scattered photons with different k-vectors) and additional waveguide scattered photons with different k-vectors.

We obtained sub-Doppler cooled temperatures of membrane MOT atoms as shown in Fig. 5, which means the membrane MOT will be practical for real-world applications. Starting from steady-state MOTs, polarization gradient (PG) cooling sequence ($\sim 1-2$ ms) is performed with intensity lowering and frequency ramping while keeping the quadrupole magnetic field on. We measured atom temperature with time-of-flight measurement after sub-Doppler cooling. The temperatures of the free-space MOT atoms ($d_{MOT} = 3.8 \text{ mm}$), membrane MOT atoms ($d_{Hole} = 0.4, 0.6, 1.0 \text{ mm}$), and bridged membrane MOT atoms ($d_{Hole} = 1.0 \text{ mm}$) are similar. The bridged section of the membrane MOT device imitates a 3-µm-width membrane ridge waveguide across the membrane hole. The horizontal temperature (T_H) corresponds to the temperature of atoms on the plane of four horizontal laser cooling beams, and the vertical temperature (T_V) corresponds to the temperature of atoms along the gravity axis of two vertical laser cooling beams as shown in Fig. 1b. Both horizontal and vertical temperature follow the trend of the time of flight (TOF) measurements even though the membrane MOT devices affect the expansion of atoms and there is some uncertainty in estimating the temperature inside the membrane. The temperature of membrane MOTs (blue square) shows a bit lower temperature than the free-space MOT (black circle). This could be due to hotter atoms colliding with the membrane and disappearing before the time-of-flight detection. The total atom number decreases, but we can achieve a colder cloud inside the hole. The lowest cloud temperature of the membrane MOT devices ($d_{Hole} = 0.4$ mm, blue square) is 5.3 μ K. The lowest measurable cloud temperature of the bridged membrane MOT devices ($d_{Hole}=1.0$ mm, red triangle) is 9.7 μ K. In the temperature measurement of the sub-Doppler cooled membrane-MOT atoms, the atom number at the membrane hole appears to drop off with drop time as the MOT atoms expand and approach to the membrane. However, the $1/\beta$ MOT lifetime measurement of the Doppler cooled membrane-MOT atoms (Fig. 4b) would not limit the atom number on the time scale (1-to-5 ms) of the time-of-flight, temperature measurement. In particular, the MOT lifetime of the bridged membrane was lower than that of other membranes. This will require further study in future investigations.

Conclusion

We developed membrane MOT devices capable of capturing 10^5 cold atoms in a sub-millimeter diameter center hole of a transparent membrane. Sub-Doppler cooling in the membrane MOT was demonstrated with the temperature of $10\,\mu$ K. This membrane device can accumulate many atoms at the center of the membrane hole during the laser cooling process, and atoms can dissipate kinetic energy and relax into the center hole without entering the other hemisphere atom loading zone. This device was designed to improve the localization of cold atoms onto the suspended membrane ridge waveguide. By implementing the membrane hole, we achieve efficient atom loading around the suspended waveguide by leveraging two large hemispherical MOT capture volumes. This device can enable photonic atom trap integrated platforms (ATIP) 50 with neutral atoms providing scalability, homogeneous physical properties, long coherence and lifetimes, and room-temperature operability. Membrane MOT devices with integrated photonics can utilize the guided, evanescent-field modes to trap and interface atoms. In addition, integrated photonics/electronics can be fabricated on the membrane device to enable advanced integration required for quantum applications.

Received: 12 November 2020; Accepted: 31 March 2021

Published online: 22 April 2021

References

- 1. Weiss, D. S. & Saffman, M. Quantum computing with neutral atoms. Phys. Today 70, 744 (2017).
- Alzar, C. L. G. Compact chip-scale guided cold atom gyrometers for inertial navigation: Enabling technologies and design study. AVS Ouant. Sci. 1 (2019).
- 3. DiVincenzo, D. P. The physical implementation of quantum computation. Fortsch. Phys. 48, 771-783 (2000).
- Duan, L. M., Lukin, M. D., Cirac, J. I. & Zoller, P. Long-distance quantum communication with atomic ensembles and linear optics. Nature 414, 413–418 (2001).
- Qi, X., Jau, Y.-Y. & Deutsch, I. H. Enhanced cooperativity for quantum-nondemolition-measurement-induced spin squeezing of atoms coupled to a nanophotonic waveguide. Phys. Rev. A 97 (2018).
- 6. Barclay, P. E., Srinivasan, K., Painter, O., Lev, B. & Mabuchi, H. Integration of fiber-coupled high-Q SiNx microdisks with atom chips. *Appl. Phys. Lett.* **89** (2006).
- Stern, L., Desiatov, B., Goykhman, I. & Levy, U. Nanoscale light-matter interactions in atomic cladding waveguides. Nat. Commun. 4, 1548 (2013).
- 8. Lee, J., Park, D. H., Mittal, M., Dagenais, M. & Rolston, S. L. Integrated optical dipole trap for cold neutral atoms with an optical waveguide coupler. N. J. Phys. 15 043010 (2013).
- 9. Tiecke, T. G. et al. Nanophotonic quantum phase switch with a single atom. Nature 508, 241-244 (2014).
- 10. Goban, A. et al. Superradiance for atoms trapped along a photonic crystal waveguide. Phys. Rev. Lett. 115 (2015).
- Meng, Y., Lee, J., Dagenais, M. & Rolston, S. L. A nanowaveguide platform for collective atom-light interaction. Appl. Phys. Lett. 107 (2015).
- 12. Stievater, T. H. et al. Modal characterization of nanophotonic waveguides for atom trapping. Opt. Mater. Express 6, 3826–3837 (2016).
- 13. Black, A. T. et al. A hybrid nanophotonic-magnetic chip-based atom trap. Opt. Soc. Am. FM2H.4 (2018).
- 14. Ritter, R. et al. Coupling Thermal atomic vapor to slot waveguides. Phys. Rev. X 8 (2018).
- 15. Kim, M. E., Chang, T.-H., Fields, B. M., Chen, C.-A. & Hung, C.-L. Trapping single atoms on a nanophotonic circuit with configurable tweezer lattices. *Nat. Commun.* 10, 1647 (2019).
- Da Ros, E., Cooper, N., Nute, J. & Hackermueller, L. Cold atoms in micromachined waveguides: A new platform for atom-photon interactions. *Phys. Rev. Res.* 2 (2020).
- 17. Béguin, J.-B. et al. Advanced apparatus for the integration of nanophotonics and cold atoms. Optica 7(1), 1-2 (2020).
- 18. Shimizu, F., Shimizu, K. & Takuma, H. Four-beam laser trap of neutral atoms. Opt. Lett. 16, 339–341 (1991).
- 19. Lee, K. I., Kim, J. A., Noh, H. R. & Jhe, W. Single-beam atom trap in a pyramidal and conical hollow mirror. Opt. Lett. 21, 1177–1179 (1996).
- Pollock, S., Cotter, J. P., Laliotis, A. & Hinds, E. A. Integrated magneto-optical traps on a chip using silicon pyramid structures. Opt. Express 17, 14109–14114 (2009).
- 21. Vangeleyn, M., Griffin, P. F., Riis, E. & Arnold, A. S. Laser cooling with a single laser beam and a planar diffractor. *Opt. Lett.* 35, 3453–3455 (2010).
- 22. Nshii, C. C. et al. A surface-patterned chip as a strong source of ultracold atoms for quantum technologies. Nat. Nanotechnol. 8, 321–324 (2013).
- 23. Lee, J., Grover, J. A., Orozco, L. A. & Rolston, S. L. Sub-Doppler cooling of neutral atoms in a grating magneto-optical trap. *J. Opt. Soc. Am. B* 30(11), 2869–2874 (2013).
- 24. Hinton, A. *et al.* A portable magneto-optical trap with prospects for atom interferometry in civil engineering. *Philos. Trans. R. Soc.* A 375, 20160238 (2016).
- 25. Imhof, E. *et al.* Two-dimensional grating magneto-optical trap. *Phys. Rev. A* **96** (2017).
- 26. McGilligan, J. P. et al. Grating chips for quantum technologies. Sci. Rep. 384, 7 (2017).
- 27. Reichel, J., Hänsel, W. & Hänsch, T. W. Atomic micromanipulation with magnetic surface traps. *Phys. Rev. Lett* 83, 3398–3401 (1999).
- 28. Folman, R. et al. Controlling cold atoms using nanofabricated surfaces: Atom chips. Phys. Rev. Lett. 84, 4749 (2000).
- 29. Brugger, K. et al. Two-wire guides and traps with vertical bias fields on atom chip. Phys. Rev. A 72 (2005).
- 30. Schwindt, P. D. D., Cornell, E. A., Kishimoto, T., Wang, Y.-J., & Anderson, D. Z. Efficient loading of a magnetic waveguide on an atom chip. *Phys. Rev. A* 72 023612 (2005).
- Colombe, Y. et al. Strong atom-field coupling for Bose–Einstein condensates in an optical cavity on a chip. Nature 450, 272–276 (2007).
- 32. Salim, E. A., Caliga, S. C., Pfeiffer, J. B. & Anderson, D. Z. High resolution imaging and optical control of Bose–Einstein condensates in an atom chip magnetic trap. *App. Phys. Lett.* **102** (2013).

- 33. Rushton, J. A., Aldous, M. & Himsworth, M. D. Contributed Rriew: The feasibility of a fully miniaturized magneto-optical trap for portable ultracold quantum technology. *Rev. Sci. Instrum.* **85** (2014).
- 34. Keil, M. et al. Fifteen years of cold matter on the atom chip: Promise, realizations, and prospects. J. Mod. Opt. 63(18), 1840–1885 (2016).
- 35. Verdú, J. et al. Strong magnetic coupling of an ultracold gas to a superconducting waveguide cavity. Phys. Rev. Lett. 103 (2009).
- 36. Hoffman, J. E. et al. Atoms talking to SQUIDs. Rev. Mex. Fis. S 57, 1 (2011).
- 37. Rolston, S. et al. A hybrid quantum system of atoms trapped on ultrathin optical fibers coupled to superconductors. Quant. Commun. Quant. Imaging XI Proc. SPIE 8875, 88750L (2013).
- 38. Kurizki, Gershon et al. Quantum technologies with hybrid systems. PNAS 112(13), 3866-3873 (2015).
- Lee, J. & Park, D. H. Protection layers on a superconducting microwave resonator toward a hybrid quantum system. J. Appl. Phys. 115, (2015).
- 40. Hattermann, H. et al. Coupling ultracold atoms to a superconducting coplanar waveguide resonator. Nat. Commun. 8, 2254 (2017).
- 41. Elshaari, A. W., Pernice, W., Srinivasan, K., Benson, O. & Zwiller, V. Hybrid integrated quantum photonic circuits. *Nat. Photon.* 14, 285–298 (2020).
- 42. Kodigala, A. et al.. Silicon photonic single-sideband generation with dual-parallel mach-zehnder modulators. Opt. Soc. Am., CLEO: Science and Innovations, STh4N.6 (2019).
- 43. Rakholia, A. V., McGuinness, H. J. & Biedermann, G. W. Dual-axis high-data-rate atom interferometer via cold ensemble exchange. *Phys. Rev. Appl.* 2, (2014).
- 44. Knight, W. İBM Raises the Bar with a 50-Qubit Quantum Computer (MIT Technology Review, 2017).
- 45. Arute, F. et al. Quantum supremacy using a programmable superconducting processor. Nature 574, 505-510 (2019).
- Zhang, J. et al. Observation of a many-body dynamical phase transition with a 53-qubit quantum simulator. Nature 551, 601-604 (2017).
- 47. Niffenegger, R. J. et al. Integrated multi-wavelength control of an ion qubit. Nature 586, 538-542 (2020).
- 48. Reilly, D. J. Engineering the quantum-classical interface of solid-state qubits. NPJ Quant. Inf. 1, 15011 (2015).
- 49. Ovchinnikov, Y. B. & Ayi-Yovo, F. E. Towards all-optical atom chips based on optical waveguides. N. J. Phys. 22, 053003 (2020).
- Gehl, M. et al. Characterization of Suspended Membrane Waveguides towards a Photonic Atom Trap Integrated Platform. Opt. Express (2021). https://doi.org/10.1364/OE.418986
- 51. Schröder, T. et al. Quantum nanophotonics in diamond. J. Opt. Soc. Am. 33(4), B65-B83 (2016).
- 52. Popkin, G. Quest for qubits. Science 354(6316), 1090-1093 (2016).
- 53. Vetsch, E. et al. Optical interface created by laser-cooled atoms trapped in the evanescent field surrounding an optical nanofiber. Phys. Rev. Lett. 104 (2010).
- 54. Lee, J., Grover, J. A., Hoffman, J. E., Orozco, L. A. & Rolston, S. L. Inhomogeneous broadening of optical transitions of 87Rb atoms in an optical nanofiber trap. *J. Phys. B* 48, 165004 (2015).
- 55. Østfeldt, C. et al. Dipole force free optical control and cooling of nanofiber trapped atoms. 42, 4315-4318 (2017).
- Kato, S. et al. Observation of dressed states of distant atoms with delocalized photons in coupled-cavities quantum electrodynamics. Nat. Commun. 10, 1160 (2019).
- 57. Jau, Y.-Y. & Lee, J. Microfabricated waveguide atom traps. United States. Web. https://doi.org/10.2172/1396077 (2017).
- 58. Dalibard, J. & Cohen-Tannoudji, C. Laser cooling below the Doppler limit by polarization gradients: Simple theoretical models. *J. Opt. Soc. Am. B* 6, 2023–2045 (1989).
- 59. Ungar, P. J., Weiss, D. S., Riis, E. & Chu, S. Optical molasses and multilevel atoms: Theory. J. Opt. Soc. Am. B 6, 2058–2071 (1989).
- 60. Sheehy, B., Shang, S.-Q., van der Straten, P., Hatamian, S. & Metcalf, H. Magnetic-field-induced laser cooling below the Doppler limit. *Phys. Rev. Lett.* **64**, 858–861 (1990).
- 61. Walhout, M., Dalibard, J., Rolston, S. L. & Phillips, W. D. $\sigma^+ \sigma^-$ Optical molasses in a longitudinal magnetic field. *J. Opt. Soc. Am. B* **9**, 1997–2007 (1992).
- 62. Lindquist, K., Stephens, M. & Wieman, C. Experimental and theoretical study of the vapor-cell Zeeman optical trap. *Phys. Rev. A* 46, 4082 (1992).
- 63. Gibble, K. E., Kasapi, S. & Chu, S. Improved magneto-optic trapping in a vapor cell. Opt. Lett. 17, 526 (1992).
- 64. Hoth, G. W., Donley, E. A., & Kitching, J. Atom number in magneto-optic traps with millimeter scale laser beams. *Opt. Lett.* 38, 5 (2013)
- 65. Ma, J., Kishinevski, A., Jau, Y.-Y., Reuter, C. & Happer, W. Modification of glass cell walls by rubidium vapor. *Phys. Rev. A* 79, (2009).
- 66. Steane, A. M., Chowdhury, M. & Foot, C. J. Radiation force in the magneto-optical trap. Opt. Soc. Am. B 9, 2142 (1992).
- 67. Pollock, S., Cotter, J. P., Laliotis, A., Ramirez-Martinez, F. & Hinds, E. A. Characteristics of integrated magneto-optical traps for atom chips. N. J. Phys. 13 (2011).

Acknowledgements

We thank Peter Schwindt, Matt Eichenfield and Aleem Siddiqui for their support and helpful discussion. This work was supported by the Laboratory Directed Research and Development program at Sandia National Laboratories. Sandia National Laboratories is a multimission laboratory managed and operated by National Technology and Engineering Solutions of Sandia, LLC., a wholly owned subsidiary of Honeywell International, Inc., for the U.S. Department of Energy's National Nuclear Security Administration under contract DE-NA-0003525. This paper describes objective technical results and analysis. Any subjective views or opinions that might be expressed in the paper do not necessarily represent the views of the U.S. Department of Energy or the United States Government.

Author contributions

Y.-Y.J., the principal investigator, conceived experiments and conducted initial experiments and simulations. J.L. and G.B. conducted the experiments and analyzed the results, and J.L. wrote the manuscript. J.M. and E.D. fabricated membrane MOT devices. All authors reviewed the manuscript.

Competing interests

The authors declare no competing interests.

Additional information

Correspondence and requests for materials should be addressed to J.L.

Reprints and permissions information is available at www.nature.com/reprints.

Publisher's note Springer Nature remains neutral with regard to jurisdictional claims in published maps and institutional affiliations.

Open Access This article is licensed under a Creative Commons Attribution 4.0 International License, which permits use, sharing, adaptation, distribution and reproduction in any medium or format, as long as you give appropriate credit to the original author(s) and the source, provide a link to the Creative Commons licence, and indicate if changes were made. The images or other third party material in this article are included in the article's Creative Commons licence, unless indicated otherwise in a credit line to the material. If material is not included in the article's Creative Commons licence and your intended use is not permitted by statutory regulation or exceeds the permitted use, you will need to obtain permission directly from the copyright holder. To view a copy of this licence, visit http://creativecommons.org/licenses/by/4.0/.

This is a U.S. Government work and not under copyright protection in the US; foreign copyright protection may apply 2021